



Support & training



SCLS539G – AUGUST 2003 – REVISED MARCH 2023

SN74LV595A-Q1 8-Bit Shift Registers With 3-State Output Registers

1 Features

- Qualified for automotive applications
- Available in wettable flank QFN (WBQB) package
- Customer-specific configuration control can be supported along with major-change approval
- 2-V to 5.5-V V_{CC} operation
- Typical V_{OLP} (output ground bounce) < 0.8 V at V_{CC} = 3.3 V, T_A = 25°C
- Typical V_{OHV} (output V_{OH} undershoot) > 2.3 V at V_{CC} = 3.3 V, T_A = 25°C
- Supports mixed-mode voltage operation on all ports
- 8-bit serial-in, parallel-out shift
- I_{off} supports partial-power-down mode operation
- · Shift register has direct clear

2 Applications

- Output expansion
- LED matrix control
- 7-segment display control

3 Description

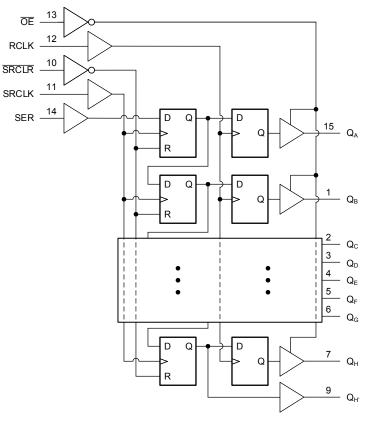
The SN74LV595A-Q1 contains an 8-bit serial-in, parallel-out shift register that feeds an 8-bit D-type storage register. The storage register has parallel 3-state outputs. Separate clocks are provided for both the shift and storage register. The shift register has a direct overriding clear (SRCLR) input, serial (SER) input, and a serial output for cascading. When the output-enable (\overline{OE}) input is high, all outputs except Q_{H'} are in the high-impedance state.

The device is fully specified for partial-power-down applications using I_{off} . The I_{off} circuitry disables the outputs, preventing damaging current backflow through the device when it is powered down.

Package Information⁽¹⁾

PART NUMBER	PACKAGE	BODY SIZE (NOM)
SN74LV595A-Q1	PW (TSSOP, 16)	5.00 mm × 4.40 mm
SIN/4LV 395A-QT	WBQB (WQFN, 16)	3.60 mm × 2.60 mm

 For all available packages, see the orderable addendum at the end of the data sheet.



Logic Diagram (Positive Logic)

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4 Revision History

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

С	Changes from Revision F (November 2022) to Revision G (March 2023)	Page
	Updated structural layout of document to current standards Updated thermal values for PW package from RθJA = 108 to 138.7, RθJC(top) = 40.8 to 69.1, RθJB = 81.8, ΨJT = 3.8 to 20.3, ΨJB = 50.6 to 81.3, all values in °C/W	= 51.1 to
С	Changes from Revision E (June 2022) to Revision F (November 2022)	Page

•	Changed the status of the data sheet from: Advanced Information to: Production Data	1
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5 Pin Configuration and Functions

	10	16	Ucc
	2	15	Q _A
	3	14	💷 SER
	4	13	
	5	12	
	6	11	SRCLK
QH 🗖	7	10	
GND 🗆	8	9	Qн′

Figure 5-1. PW Package, 16-Pin TSSOP (Top View)

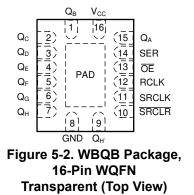


Table 5-1. Pin Functions

PIN		TYPE ⁽¹⁾	DESCRIPTION		
NAME	NO.				
GND	8	G	Ground		
ŌĒ	13	I	Output Enable Pin		
Q _A	15	0	Q _A Output		
Q _B	1	0	Q _B Output		
Q _C	2	0	Q _C Output		
Q _D	3	0	Q _D Output		
Q _E	4	0	Q _E Output		
Q _F	5	0	Output		
Q _G	6	0	Q _G Output		
Q _H	7	0	Q _H Output		
Q _{H'}	9	0	Q _H Output		
SRCLR	10	I	SRCLR Input		
SRCLK	11	I	SRCLK Input		
RCLK	12	I	RCLK Input		
SER	14	I	SER Input		
V _{CC}	16	Р	Positive Supply		
PAD			Thermal Pad ⁽²⁾		

(1) I = Input, O = Output, I/O = Input or Output, G = Ground, P = Power.

(2) WBQB Package Only



6 Specifications 6.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)⁽¹⁾

			MIN	MAX	UNIT
V _{CC}	Supply voltage range		-0.5	7.0	V
VI	Input voltage range ⁽²⁾	nput voltage range ⁽²⁾			
v	Voltage range applied to ar	y output in the high-impedance or power-off state ⁽²⁾	-0.5	4.6	V
Vo	Output voltage range applie	ed to any output in the high or low state ^{(2) (3)}	-0.5	V _{CC} + 0.5	V
I _{IK}	Input clamp current ⁽²⁾	V ₁ < 0		-20	mA
I _{ок}	Output clamp current ⁽²⁾	V ₀ < 0		-50	mA
I _O	Continuous output current			±35	mA
	Continuous current through	V _{CC} or GND		±70	mA
TJ	Junction temperature			150	°C
T _{stg}	Storage temperature		-65	150	°C

(1) Stresses beyond those listed under *Absolute Maximum Ratings* may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under *Recommended Operating Conditions* is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

(2) The input negative-voltage and output voltage ratings may be exceeded if the input and output current ratings are observed.

(3) The package thermal impedance is calculated in accordance with JESD 51-7.

6.2 ESD Ratings

			VALUE	UNIT
		Human-body model (HBM), per AEC Q100-002 HBM ESD Classification Level 2 ⁽¹⁾	±2000	
V _(ESD)	Electrostatic discharge	Machine Model (MM), per JEDEC specification	±200	V
	aleenalge	Charged-device model (CDM), per AEC Q100-011 CDM ESD Classification Level C4B	±1000	

(1) AEC Q100-002 indicate that HBM stressing shall be in accordance with the ANSI/ESDA/JEDEC JS-001 specification.



6.3 Recommended Operating Conditions

			MIN	MAX	UNIT			
V _{CC}	Supply voltage		2	5.5	V			
		V _{CC} = 2 V	1.5					
V		V_{CC} = 2.3 V to 2.7 V	V _{CC} × 0.7		V			
V _{IH}	High-level input voltage	V _{CC} = 3 V to 3.6 V	V _{CC} × 0.7		v			
		V_{CC} = 4.5 V to 5.5 V	V _{CC} × 0.7					
		V _{CC} = 2 V		0.5				
	Low-level input voltage	V _{CC} = 2.3 V to 2.7 V		V _{CC} × 0.3	v			
V _{IL}		V _{CC} = 3 V to 3.6 V		V _{CC} × 0.3	V			
		V _{CC} = 4.5 V to 5.5 V		V _{CC} × 0.3				
VI	Input voltage ⁽¹⁾	1	0	5.5	V			
Vo	Output wells and	High or low state	0	V _{CC}	V			
	Output voltage	3-state	0	5.5				
		V _{CC} = 2 V		-50	μA			
	High level output current	V _{CC} = 2.3 V to 2.7 V		-2	mA			
I _{OH}		V _{CC} = 3 V to 3.6 V		-8				
		V_{CC} = 4.5 V to 5.5 V		-16				
		V _{CC} = 2 V		50	μA			
		V _{CC} = 2.3 V to 2.7 V		2				
I _{OL}	Low level output current	V _{CC} = 3 V to 3.6 V		8	mA			
		V _{CC} = 4.5 V to 5.5 V		16				
		V _{CC} = 2.3 V to 2.7 V		200				
∆t/∆v	Input transition rise/fall time	V _{CC} = 3 V to 3.6 V		100	ns/V			
		$V_{CC} = 4.5 V \text{ to } 5.5 V$		20				
		SN74LV595AIPWRQ1	-40	85				
T _A	Operating free-air temperature	SN74LV595AQPWRQ1 or SN74LV595AQWBQRQ1	-40	125	°C			

(1) All unused inputs of the device must be held at V_{CC} or GND to ensure proper device operation. See the TI application report, *Implications of Slow or Floating CMOS Inputs*.

6.4 Thermal Information

		SN74L\		
	THERMAL METRIC ⁽¹⁾	PW (TSSOP)	WBQB (WQFN)	UNIT
		16 PINS	16 PINS	
R _{θJA}	Junction-to-ambient thermal resistance	138.7	86	°C/W
R _{0JC(top)}	Junction-to-case (top) thermal resistance	69.1	82.6	°C/W
$R_{\theta JB}$	Junction-to-board thermal resistance	81.8	54.9	°C/W
Ψ_{JT}	Junction-to-top characterization parameter	20.3	9.5	°C/W
Ψ_{JB}	Junction-to-board characterization parameter	81.3	54.9	°C/W
R _{0JC(bot)}	Junction-to-case (bottom) thermal resistance	N/A	32.5	°C/W

(1) For more information about traditional and new thermal metrics, see the IC Package Thermal Metrics application report, SPRA953.



6.5 Electrical Characteristics

DADAMETER	TEST CONDITIONS		V V	–40°C to 85°C			–40°C to 125°C			UNIT
PARAMETER			V _{cc}	MIN	TYP	MAX	MIN	ТҮР	MAX	UNIT
		I _{OH} = –50 μA	2 V to 5.5 V	V _{CC} - 0.1			V _{CC} – 0.1			
		I _{OH} = -2 mA	2.3 V	2			2			
V	Q _H ,	I _{OH} =6 mA	3 V	2.48			2.45			- V
V _{OH}	Q _A –Q _H	I _{OH} =8 mA	3 V	2.48			2.45			
	Q _{H'}	I _{OH} = -12 mA	4 5 \/	3.8			3.7			
	Q _A –Q _H	I _{OH} = -16 mA	- 4.5 V -	3.8			3.7			
		I _{OL} = 50 μA	2 V to 5.5 V			0.1			0.1	
		I _{OL} = 2 mA	2.3 V			0.4			0.45	
N	Q _{H'}	I _{OL} = 6 mA	3 V			0.44			0.5	V
V _{OL}	Q _A -Q _H	I _{OL} = 8 mA	3 V			0.44			0.5	v
	Q _{H'}	I _{OL} = 12 mA	4 5 1 4			0.55			0.65	
	Q _A -Q _H	I _{OL} = 16 mA	4.5 V			0.55			0.65	
I _I	V _I = 5.5 V or G	ND	0 to 5.5 V			±1			±1	μA
I _{OZ}	$Q_A - Q_H$	$V_0 = V_{CC}$ or GND,	5.5 V			±5			±10	μA
I _{CC}	$V_{I} = V_{CC}$ or GN	ID, I _O = 0	5.5 V			20			40	μA
l _{off}	V_{I} or V_{O} = 0 to 5.5 V		0 V			5			10	μA
C _i	V _I = V _{CC} or GN	ID	3.3 V		3.5			3.5		pF

over recommended operating free-air temperature range (unless otherwise noted)

6.6 Timing Requirements, V_{CC} = 2.5 V ± 0.2 V

over operating free-air temperature range (unless otherwise noted)

			T _A = 2	25°C	T _A = TO 8		T _A = -4 TO 12		UNIT
			MIN	MAX	MIN	MAX	MIN	MAX	
		SRCLK high or low	7		7.5		8.5		
tw	Pulse duration	RCLK high or low	7		7.5		8.5		ns
		SRCLR low 6		6.5		7.5			
		SER before SRCLK↑	5.5		5.5		6.5		
	Cature time a	SRCLK↑ before RCLK↑ ⁽¹⁾	8		9		10		
t _{su}	Setup time	SRCLR low before RCLK↑	8.5		9.5		10.5		ns
		SRCLR high (inactive) before SRCLK↑	4		4		5		
t _h	Hold time	SER after SRCLK↑	1.5		1.5		2.5		ns

(1) This setup time allows the storage register to receive stable data from the shift register. The clocks can be tied together, in which case the shift register is one clock pulse ahead of the storage register.



6.7 Timing Requirements, V_{CC} = 3.3 V ± 0.3 V

over operating free-air temperature range (unless otherwise noted)

			T _A = 2	5°C	T _A = -4 TO 8		T _A = -4 TO 12		UNIT
			MIN	MAX	MIN	MAX	MIN	MAX	
		SRCLK high or low	5.5		5.5		6.5		
tw	Pulse duration	RCLK high or low	5.5		5.5		6.5		ns
		SRCLR low	5		5		6		
		SER before SRCLK↑	3.5		3.5		4.5		
	Cotup time	SRCLK↑ before RCLK↑ ⁽¹⁾	8		8.5		9.5		
t _{su}	Setup time	SRCLR low before RCLK↑	8		9		10		ns
		SRCLR high (inactive) before SRCLK↑	3		3	3 4			
t _h	Hold time	SER after SRCLK↑	1.5		1.5		2.5		ns

(1) This setup time allows the storage register to receive stable data from the shift register. The clocks can be tied together, in which case the shift register is one clock pulse ahead of the storage register.

6.8 Timing Requirements, V_{CC} = 5 V ± 0.5 V

over operating free-air temperature range (unless otherwise noted)

			T _A = 2	5°C	T _A = - TO 8		T _A = -4 TO 12		UNIT
			MIN	MAX	MIN	MAX	MIN	MAX	
		SRCLK high or low	5		5		6		
tw	Pulse duration	RCLK high or low	5		5		6		ns
		SRCLR low	5.2		5.2		6.2		
		SER before SRCLK↑	3		3		4		
	Cotup time	SRCLK↑ before RCLK↑ ⁽¹⁾	5		5		6		
t _{su}	Setup time	SRCLR low before RCLK↑	5		5		6		ns
		SRCLR high (inactive) before SRCLK↑	2.5		2.5		3.5		
t _h	Hold time	SER after SRCLK↑	2		2		3		ns

(1) This setup time allows the storage register to receive stable data from the shift register. The clocks can be tied together, in which case the shift register is one clock pulse ahead of the storage register.

6.9 Switching Characteristics, V_{CC} = 2.5 V ± 0.2 V

over recommended operating free-air temperature range, $C_L = 50 \text{ pF}$ (unless otherwise noted)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	Τ ₄	= 25°C		T _A = -4 TO 8		T _A = -4 TO 12		UNIT MHz ns ns ns ns ns ns ns
	(INFOT)	(001201)	MIN	TYP	MAX	MIN	MAX	MIN	MAX	
f _{max}			60	70		40		30		MHz
t _{PLH}	RCLK	0 -0		11.2	17.2	1	19.3	1	22.3	ns
t _{PHL}	ROLK	Q _A -Q _H		11.2	17.2	1	19.3	1	22.3	ns
t _{PLH}	SRCLK	0		13.1	22.5	1	25.5	1	28.5	ns
t _{PHL}	SKOLK	Q _{H'}		13.1	22.5	1	25.5	1	28.5	ns
t _{PHL}	SRCLR	Q _H '		12.4	18.8	1	21.1	1	24.1	ns
t _{PZH}	ŌĒ	0.0		10.8	17	1	18.3	1	21.3	ns
t _{PZL}	UE	Q _A –Q _H		13.4	21	1	23	1	26	ns
t _{PHZ}	ŌĒ	0 -0		12.2	18.3	1	19.5	1	22.5	ns
t _{PLZ}	UE	Q _A –Q _H		14	20.9	1	22.6	1	25.6	ns

6.10 Switching Characteristics, V_{CC} = 3.3 V ± 0.3 V

over recommended operating free-air temperature range, $C_L = 50 \text{ pF}$ (unless otherwise noted)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	Tړ	⊆ 25°C		T _A = -4 TO 8		T _A = -4 TO 12		UNIT	
	(INFOT)		MIN	TYP	MAX	MIN	MAX	MIN	MAX		
f _{max}			55	105		50		40		MHz	
t _{PLH}	RCLK	0 -0		7.9	15.4	1	17	1	20	ns	
t _{PHL}	KULK	Q _A -Q _H		7.9	15.4	1	17	1	20	ns	
t _{PLH}	SRCLK	Q _{H'}		9.2	16.5	1	18.5	1	21.5	ns	
t _{PHL}	SRULK			9.2	16.5	1	18.5	1	21.5	ns	
t _{PHL}	SRCLR	Q _{H'}		9	16.3	1	17.2	1	20.2	ns	
t _{PZH}	OE	0 -0		7.8	15	1	17	1	20	ns	
t _{PZL}	UE	Q _A –Q _H		9.6	15	1	17	1	20	ns	
t _{PHZ}	ŌĒ	0 -0		8.1	15.7	1	16.2	1	19.2	ns	
t _{PLZ}		Q _A -Q _H		9.3	15.7	1	16.2	1	19.2	ns	

6.11 Switching Characteristics, V_{CC} = 5 V \pm 0.5 V

over recommended operating free-air temperature range, C_L = 50 pF (unless otherwise noted)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	Tے	√ = 25°C		T _A = -4 TO 8		T _A = -4 TO 12		MHz ns ns ns
	(INPUT)	(001201)	MIN	TYP	MAX	MIN	MAX	MIN	MAX	
f _{max}			95	140		85		75		MHz
t _{PLH}	RCLK	0 -0		5.6	9.4	1	10.5	1	13.5	ns
t _{PHL}	NOLK	Q _A -Q _H		5.6	9.4	1	10.5	1	13.5	ns
t _{PLH}	SRCLK	0		6.4	10.2	1	11.4	1	14.4	ns
t _{PHL}	SKULK	Q _{H'}		6.4	10.2	1	11.4	1	14.4	ns
t _{PHL}	SRCLR	Q _{H'}		6.4	10	1	11.1	1	14.1	ns
t _{PZH}	ŌĒ	0 -0		5.7	10.6	1	12	1	15	ns
t _{PZL}	UE	Q _A -Q _H		6.8	10.6	1	12	1	15	ns
t _{PHZ}	ŌĒ	0.0		3.5	10.3	1	11	1	14	ns
t _{PLZ}	UE	Q _A –Q _H		3.4	10.3	1	11	1	14	ns



6.12 Timing Diagrams

SRCLK	
SER	
RCLK	
SRCLR	
ŌĒ	
Q _A	
Q _B	
Q _C	
Q_D	
Q_E	
Q_F	
Q_{G}	
Q _H	
Q _{H'}	

NOTE: XXX implies that the output is in 3-State mode.

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Figure 6-1. Timing Diagram

6.13 Noise Characteristics

 V_{CC} = 3.3 V, C_L = 50 pF, T_A = 25°C⁽¹⁾

	PARAMETER	MIN	TYP	MAX	UNIT
V _{OL(P)}	Quiet output, maximum dynamic V _{OL}		0.3		V
V _{OL(V)}	Quiet output, minimum dynamic V _{OL}		-0.2		V
V _{OH(V)}	Quiet output, minimum dynamic V _{OH}		2.8		V
V _{IH(D)}	High-level dynamic input voltage	2.31			V
V _{IL(D)}	Low-level dynamic input voltage			0.99	V

(1) Characteristics are for surface-mount packages only.

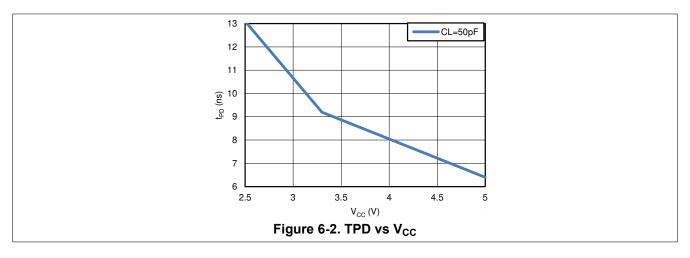


6.14 Operating Characteristics

T_A = 25°C

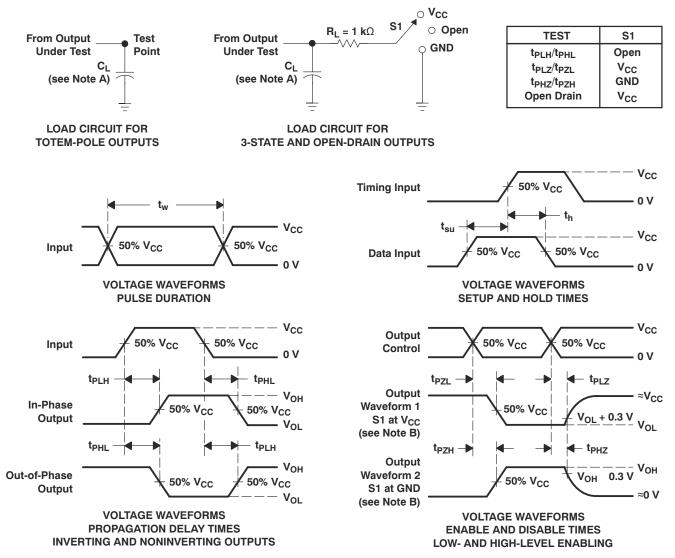
	PARAMETER	TEST CONDITION	TYP	UNIT	
C	Power discinction canacitance	C _L = 50 pF, f = 10 MHz	V _{CC} = 3.3 V	111	ъĘ
C _{pd}	Power dissipation capacitance		V _{CC} = 5 V	114	рF

6.15 Typical Characteristics





7 Parameter Measurement Information



- NOTES: A. C_{L} includes probe and jig capacitance.
 - B. Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control.
 - C. All input pulses are supplied by generators having the following characteristics: PRR \leq 1 MHz, Z₀ = 50 Ω , t_r \leq 3 ns, t_f \leq 3 ns.
 - D. The outputs are measured one at a time, with one input transition per measurement.
 - E. t_{PLZ} and t_{PHZ} are the same as t_{dis} .
 - F. t_{PZL} and t_{PZH} are the same as t_{en} .
 - G. t_{PHL} and t_{PLH} are the same as t_{pd} .
 - H. All parameters and waveforms are not applicable to all devices.

Figure 7-1. Load Circuit and Voltage Waveforms



8 Detailed Description

8.1 Overview

The SN74LV595A-Q1 contains an 8-bit serial-in, parallel-out shift register that feeds an 8-bit D-type storage register. The storage register has parallel 3-state outputs. Separate clocks are provided for both the shift and storage register. The shift register has a direct overriding clear (\overline{SRCLR}) input, serial (SER) input, and a serial output for cascading. When the output-enable (\overline{OE}) input is high, all outputs except Q_{H'} are in the high-impedance state.

Both the shift register clock (SRCLK) and storage register clock (RCLK) are positive-edge triggered. If both clocks are connected together, the shift register always is one clock pulse ahead of the storage register.

To ensure the high-impedance state during power up or power down, \overline{OE} should be tied to V_{CC} through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.

The device is fully specified for partial-power-down applications using I_{off}. The I_{off} circuitry disables the outputs, preventing damaging current backflow through the device when it is powered down.

8.2 Functional Block Diagram

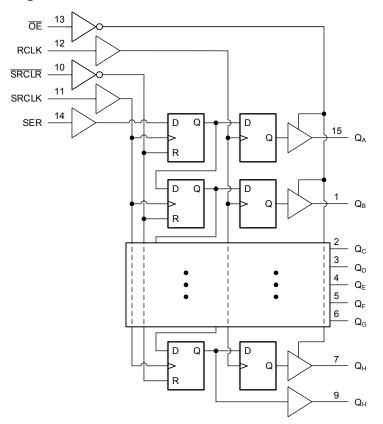


Figure 8-1. Logic Diagram (Positive Logic)



8.3 Feature Description

8.3.1 Balanced CMOS 3-State Outputs

This device includes balanced CMOS 3-state outputs. Driving high, driving low, and high impedance are the three states that these outputs can be in. The term *balanced* indicates that the device can sink and source similar currents. The drive capability of this device may create fast edges into light loads, so routing and load conditions should be considered to prevent ringing. Additionally, the outputs of this device can drive larger currents than the device can sustain without being damaged. It is important for the output power of the device to be limited to avoid damage due to overcurrent. The electrical and thermal limits defined in the *Absolute Maximum Ratings* must be followed at all times.

When placed into the high-impedance mode, the output will neither source nor sink current, with the exception of minor leakage current as defined in the *Electrical Characteristics* table. In the high-impedance state, the output voltage is not controlled by the device and is dependent on external factors. If no other drivers are connected to the node, then this is known as a floating node and the voltage is unknown. A pull-up or pull-down resistor can be connected to the output to provide a known voltage at the output while it is in the high-impedance state. The value of the resistor will depend on multiple factors, including parasitic capacitance and power consumption limitations. Typically, a $10-k\Omega$ resistor can be used to meet these requirements.

Unused 3-state CMOS outputs should be left disconnected.

8.3.2 Latching Logic

This device includes latching logic circuitry. Latching circuits commonly include D-type latches and D-type flip-flops, but include all logic circuits that act as volatile memory.

When the device is powered on, the state of each latch is unknown. There is no default state for each latch at start-up.

The output state of each latching logic circuit only remains stable as long as power is applied to the device within the supply voltage range specified in the *Recommended Operating Conditions* table.

8.3.3 Partial Power Down (I_{off})

This device includes circuitry to disable all outputs when the supply pin is held at 0 V. When disabled, the outputs will neither source nor sink current, regardless of the input voltages applied. The amount of leakage current at each output is defined by the l_{off} specification in the *Electrical Characteristics* table.



8.3.4 Wettable Flanks

This device includes wettable flanks for at least one package. See the *Features* section on the front page of the data sheet for which packages include this feature.

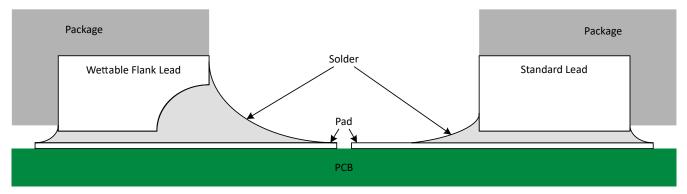


Figure 8-2. Simplified Cutaway View of Wettable-Flank QFN Package and Standard QFN Package After Soldering

Wettable flanks help improve side wetting after soldering, which makes QFN packages easier to inspect with automatic optical inspection (AOI). As shown in Figure 8-2, a wettable flank can be dimpled or step-cut to provide additional surface area for solder adhesion which assists in reliably creating a side fillet. Please see the mechanical drawing for additional details.

8.3.5 Clamp Diode Structure

Figure 8-3 shows the inputs and outputs to this device have negative clamping diodes only.

CAUTION Voltages beyond the values specified in the *Absolute Maximum Ratings* table can cause damage to the device. The input and output voltage ratings may be exceeded if the input and output clamp-current ratings are observed.

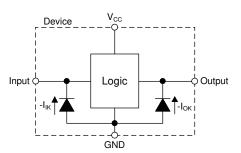


Figure 8-3. Electrical Placement of Clamping Diodes for Each Input and Output



8.4 Device Functional Modes

		INPUTS ⁽¹⁾			FUNCTION
SER	SRCLK	SRCLR	RCLK	ŌĒ	FUNCTION
x	x	х	х	н	Outputs $Q_A - Q_H$ are disabled. $Q_{H'}$ remains enabled.
Х	Х	Х	Х	L	Outputs $Q_A - Q_H$ are enabled.
Х	Х	L	Х	Х	Shift register is cleared.
L	↑ (Н	х	х	First stage of the shift register goes low. Other stages store the data of previous stage, respectively.
Н	¢	н	х	х	First stage of the shift register goes high. Other stages store the data of previous stage, respectively.
х	х	х	ſ	Х	Shift-register data is stored in the storage register.

Table 8-1. Function Table

(1) H = High Voltage Level, L = Low Voltage Level, X = Do not Care, Z = High Impedance



9 Application and Implementation

Note

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes, as well as validating and testing their design implementation to confirm system functionality.

9.1 Application Information

The SN74LV595A-Q1 is a low-drive CMOS device that can be used for a multitude of bus interface type applications where output ringing is a concern. The low drive and slow edge rates will minimize overshoot and undershoot on the outputs. The inputs are 5-V tolerant allowing for down translation to V_{CC} .

9.2 Typical Application

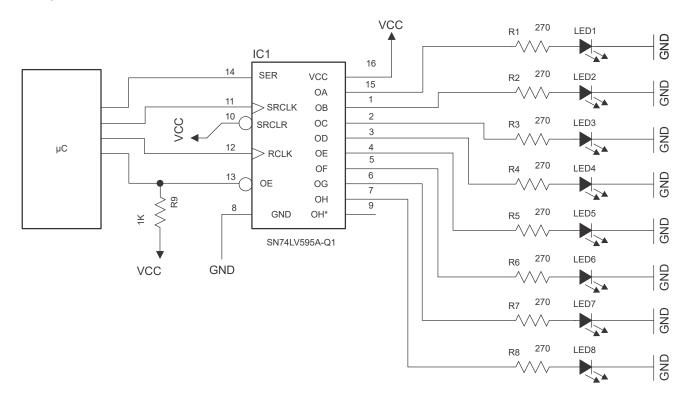


Figure 9-1. SN74LV595A-Q1 Expanding IOs to Drive LEDs

9.2.1 Power Considerations

Ensure the desired supply voltage is within the range specified in the *Recommended Operating Conditions*. The supply voltage sets the device's electrical characteristics as described in the *Electrical Characteristics* section.

The positive voltage supply must be capable of sourcing current equal to the total current to be sourced by all outputs of the SN74LV595A-Q1 plus the maximum static supply current, I_{CC} , listed in the *Electrical Characteristics*, and any transient current required for switching. The logic device can only source as much current that is provided by the positive supply source. Be sure to not exceed the maximum total current through V_{CC} listed in the *Absolute Maximum Ratings*.



The ground must be capable of sinking current equal to the total current to be sunk by all outputs of the SN74LV595A-Q1 plus the maximum supply current, I_{CC} , listed in the *Electrical Characteristics*, and any transient current required for switching. The logic device can only sink as much current that can be sunk into its ground connection. Be sure to not exceed the maximum total current through GND listed in the *Absolute Maximum Ratings*.

The SN74LV595A-Q1 can drive a load with a total capacitance less than or equal to 50 pF while still meeting all of the data sheet specifications. Larger capacitive loads can be applied; however, it is not recommended to exceed 50 pF.

The SN74LV595A-Q1 can drive a load with total resistance described by $R_L \ge V_O / I_O$, with the output voltage and current defined in the *Electrical Characteristics* table with V_{OH} and V_{OL} . When outputting in the HIGH state, the output voltage in the equation is defined as the difference between the measured output voltage and the supply voltage at the V_{CC} pin.

Total power consumption can be calculated using the information provided in *CMOS Power Consumption and Cpd Calculation*.

Thermal increase can be calculated using the information provided in *Thermal Characteristics of Standard Linear and Logic (SLL) Packages and Devices.*

CAUTION

The maximum junction temperature, $T_{J(max)}$ listed in the *Absolute Maximum Ratings*, is an additional limitation to prevent damage to the device. Do not violate any values listed in the *Absolute Maximum Ratings*. These limits are provided to prevent damage to the device.

9.2.2 Input Considerations

Input signals must cross $V_{IL(max)}$ to be considered a logic LOW, and $V_{IH(min)}$ to be considered a logic HIGH. Do not exceed the maximum input voltage range found in the *Absolute Maximum Ratings*.

Unused inputs must be terminated to either V_{CC} or ground. The unused inputs can be directly terminated if the input is completely unused, or they can be connected with a pull-up or pull-down resistor if the input will be used sometimes, but not always. A pull-up resistor is used for a default state of HIGH, and a pull-down resistor is used for a default state of LOW. The drive current of the controller, leakage current into the SN74LV595A-Q1 (as specified in the *Electrical Characteristics*), and the desired input transition rate limits the resistor size. A 10-k Ω resistor value is often used due to these factors.

The SN74LV595A-Q1 has CMOS inputs and thus requires fast input transitions to operate correctly, as defined in the *Recommended Operating Conditions* table. Slow input transitions can cause oscillations, additional power consumption, and reduction in device reliability.

Refer to the *Feature Description* section for additional information regarding the inputs for this device.

9.2.3 Output Considerations

The positive supply voltage is used to produce the output HIGH voltage. Drawing current from the output will decrease the output voltage as specified by the V_{OH} specification in the *Electrical Characteristics*. The ground voltage is used to produce the output LOW voltage. Sinking current into the output will increase the output voltage as specified by the V_{OL} specification in the *Electrical Characteristics*.

Push-pull outputs that could be in opposite states, even for a very short time period, should never be connected directly together. This can cause excessive current and damage to the device.

Two channels within the same device with the same input signals can be connected in parallel for additional output drive strength.

Unused outputs can be left floating. Do not connect outputs directly to V_{CC} or ground.

Refer to the *Feature Description* section for additional information regarding the outputs for this device.



9.2.4 Detailed Design Procedure

- Add a decoupling capacitor from V_{CC} to GND. The capacitor needs to be placed physically close to the device and electrically close to both the V_{CC} and GND pins. An example layout is shown in the *Layout* section.
- Ensure the capacitive load at the output is ≤ 50 pF. This is not a hard limit; it will, however, ensure optimal performance. This can be accomplished by providing short, appropriately sized traces from the SN74LV595A-Q1 to one or more of the receiving devices.
- 3. Ensure the resistive load at the output is larger than $(V_{CC} / I_{O(max)}) \Omega$. This will ensure that the maximum output current from the *Absolute Maximum Ratings* is not violated. Most CMOS inputs have a resistive load measured in M Ω ; much larger than the minimum calculated previously.
- 4. Thermal issues are rarely a concern for logic gates; the power consumption and thermal increase, however, can be calculated using the steps provided in the application report, *CMOS Power Consumption and Cpd Calculation*.

9.2.5 Application Curves

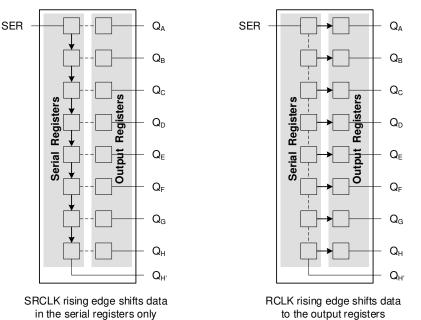


Figure 9-2. Simplified Functional Diagram Showing Clock Operation



9.3 Power Supply Recommendations

The power supply can be any voltage between the MIN and MAX supply voltage rating located in the *Recommended Operating Conditions* table.

Each V_{CC} terminal should have a good bypass capacitor to prevent power disturbance. For devices with a single supply, a 0.1 μ F capacitor is recommended. If there are multiple V_{CC} terminals then 0.01 μ F or 0.022 μ F capacitors are recommended for each power terminal. It is ok to parallel multiple bypass capacitors to reject different frequencies of noise. 0.1 μ F and 1.0 μ F capacitors are commonly used in parallel. The bypass capacitor should be installed as close to the power terminal as possible for the best results.

9.4 Layout

9.4.1 Layout Guidelines

When using multiple bit logic devices, inputs should not float. In many cases, functions or parts of functions of digital logic devices are unused. Some examples are when only two inputs of a triple-input AND gate are used, or when only 3 of the 4-buffer gates are used. Such input pins should not be left unconnected because the undefined voltages at the outside connections result in undefined operational states.

Specified in Figure 9-3 are rules that must be observed under all circumstances. All unused inputs of digital logic devices must be connected to a high or low bias to prevent them from floating. The logic level that should be applied to any particular unused input depends on the function of the device. Generally they will be tied to GND or V_{CC} , whichever makes more sense or is more convenient. It is acceptable to float outputs unless the part is a transceiver. If the transceiver has an output enable pin, it will disable the outputs section of the part when asserted. This will not disable the input section of the I/Os so they also cannot float when disabled.

9.4.2 Layout Example

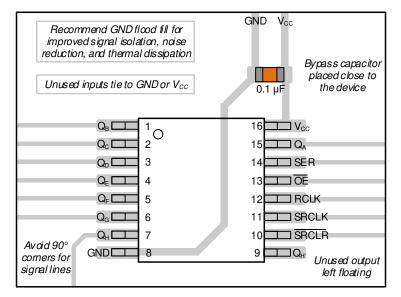


Figure 9-3. Layout Example for the SN74LV595A-Q1



10 Device and Documentation Support

10.1 Documentation Support

10.1.1 Related Documentation

For related documentation, see the following:

- · Texas Instruments, CMOS Power Consumption and Cpd Calculation application report
- Texas Instruments, Thermal Characteristics of Standard Linear and Logic (SLL) Packages and Devices appliation report

10.2 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on ti.com. Click on *Subscribe to updates* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

10.3 Support Resources

TI E2E[™] support forums are an engineer's go-to source for fast, verified answers and design help — straight from the experts. Search existing answers or ask your own question to get the quick design help you need.

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10.5 Electrostatic Discharge Caution



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

10.6 Glossary

TI Glossary This glossary lists and explains terms, acronyms, and definitions.

11 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.



PACKAGING INFORMATION

Orderable Device	Status	Package Type		Pins	-	Eco Plan	Lead finish/	MSL Peak Temp	Op Temp (°C)	Device Marking	Samples
	(1)		Drawing		Qty	(2)	Ball material	(3)		(4/5)	
SN74LV595AIPWRG4Q1	ACTIVE	TSSOP	PW	16	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	LV595AI	Samples
SN74LV595AIPWRQ1	ACTIVE	TSSOP	PW	16	2000	RoHS & Green	NIPDAU	Level-3-260C-168 HR	-40 to 85	LV595AI	Samples
SN74LV595AQPWRQ1	ACTIVE	TSSOP	PW	16	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	LV595AQ	Samples
SN74LV595AQWBQBRQ1	ACTIVE	WQFN	BQB	16	3000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	LV595Q	Samples

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

⁽²⁾ RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

⁽³⁾ MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

⁽⁴⁾ There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

⁽⁵⁾ Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

⁽⁶⁾ Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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OTHER QUALIFIED VERSIONS OF SN74LV595A-Q1 :

• Catalog : SN74LV595A

• Enhanced Product : SN74LV595A-EP

NOTE: Qualified Version Definitions:

- Catalog TI's standard catalog product
- Enhanced Product Supports Defense, Aerospace and Medical Applications



Texas

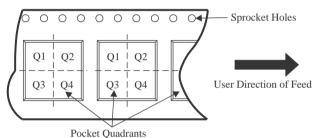
STRUMENTS

TAPE AND REEL INFORMATION





QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



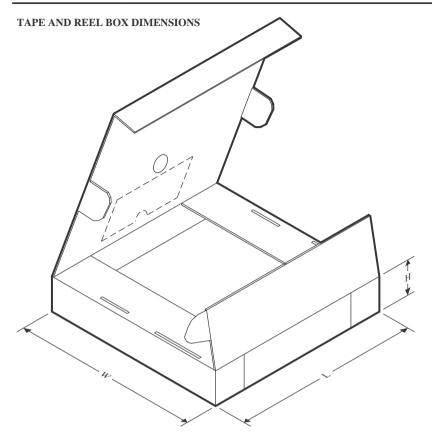
All dimensions are nominal												
Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN74LV595AIPWRG4Q1	TSSOP	PW	16	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
SN74LV595AIPWRQ1	TSSOP	PW	16	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
SN74LV595AQPWRQ1	TSSOP	PW	16	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
SN74LV595AQPWRQ1	TSSOP	PW	16	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
SN74LV595AQWBQBRQ1	WQFN	BQB	16	3000	180.0	12.4	2.8	3.8	1.2	4.0	12.0	Q1



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PACKAGE MATERIALS INFORMATION

25-Sep-2024



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN74LV595AIPWRG4Q1	TSSOP	PW	16	2000	356.0	356.0	35.0
SN74LV595AIPWRQ1	TSSOP	PW	16	2000	356.0	356.0	35.0
SN74LV595AQPWRQ1	TSSOP	PW	16	2000	353.0	353.0	32.0
SN74LV595AQPWRQ1	TSSOP	PW	16	2000	356.0	356.0	35.0
SN74LV595AQWBQBRQ1	WQFN	BQB	16	3000	210.0	185.0	35.0

PW0016A



PACKAGE OUTLINE

TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M. 2. This drawing is subject to change without notice. 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
- 5. Reference JEDEC registration MO-153.



PW0016A

EXAMPLE BOARD LAYOUT

TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



PW0016A

EXAMPLE STENCIL DESIGN

TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



NOTES: (continued)

9. Board assembly site may have different recommendations for stencil design.



^{8.} Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.

BQB 16

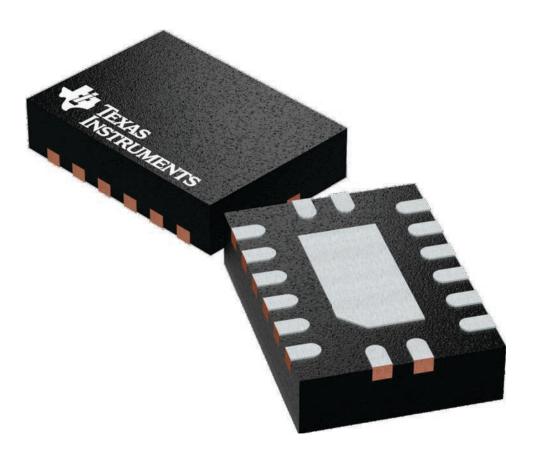
GENERIC PACKAGE VIEW

WQFN - 0.8 mm max height

PLASTIC QUAD FLATPACK - NO LEAD

2.5 x 3.5, 0.5 mm pitch

This image is a representation of the package family, actual package may vary. Refer to the product data sheet for package details.

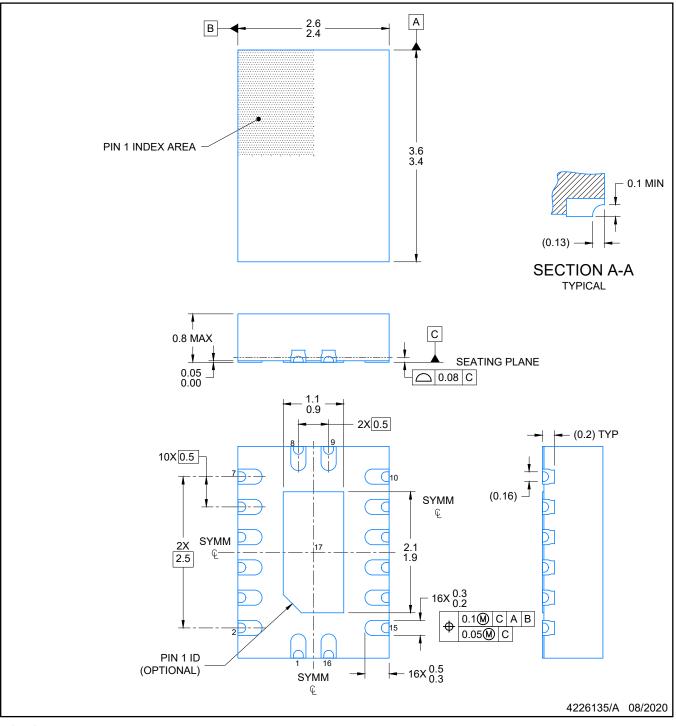




BQB0016B

PACKAGE OUTLINE WQFN - 0.8 mm max height

INDSTNAME



NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
- 2. This drawing is subject to change without notice.
- 3. The package thermal pad must be soldered to the printed circuit board for optimal thermal and mechanical performance.

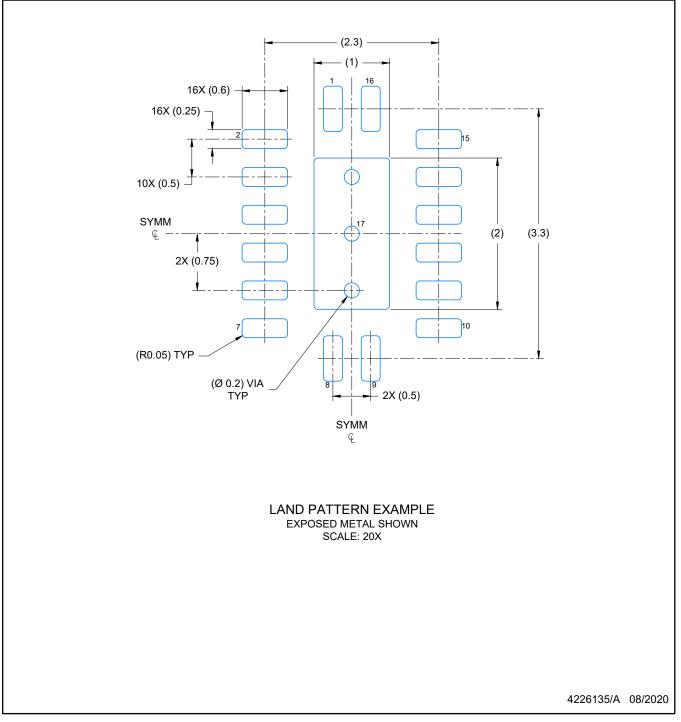


BQB0016B

EXAMPLE BOARD LAYOUT

WQFN - 0.8 mm max height

INDSTNAME



NOTES: (continued)

- 4. This package is designed to be soldered to a thermal pad on the board. For more information, see Texas Instruments literature number SLUA271 (www.ti.com/lit/slua271).
- 5. Vias are optional depending on application, refer to device data sheet. If any vias are implemented, refer to their locations shown on this view. It is recommended that vias under paste be filled, plugged or tented.

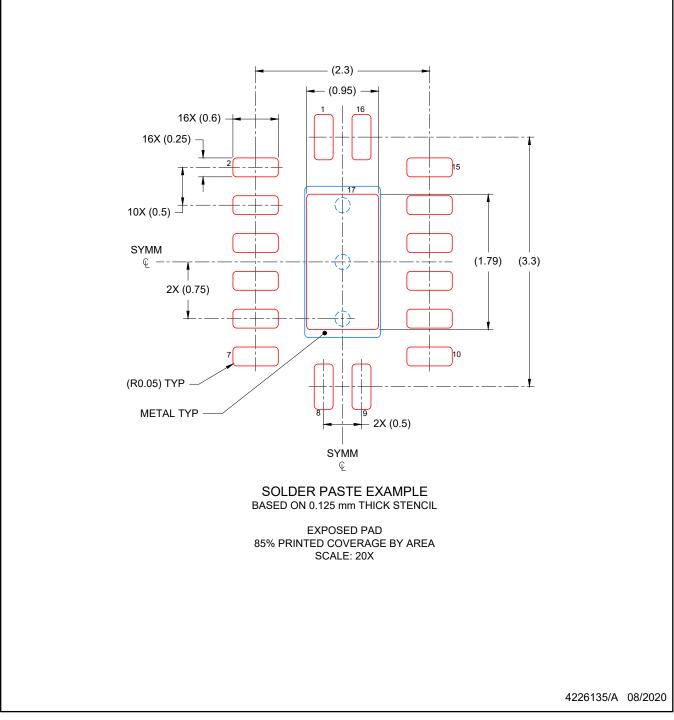


BQB0016B

EXAMPLE STENCIL DESIGN

WQFN - 0.8 mm max height

INDSTNAME



NOTES: (continued)

6. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.



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